



DMT6015LFV

60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8 (TYPE UX)

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _C = +25°C |
|-------------------|------------------------------|--|
| | 16mΩ @ V _{GS} = 10V | 35A |
| 60V | $22m\Omega @ V_{GS} = 4.5V$ | 28A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

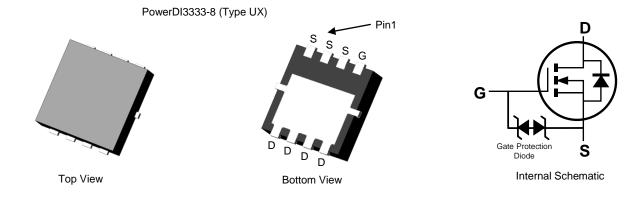
- Motor Control
- DC-DC Converters
- Power Management

Features and Benefits

- Low R_{DS(ON)} Ensures On-State Losses are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products
- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: PowerDI[®]3333-8 (Type UX)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.072 grams (Approximate)



Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|-------------------------|-------------------|
| DMT6015LFV-7 | PowerDI3333-8 (Type UX) | 2,000/Tape & Reel |
| DMT6015LFV-13 | PowerDI3333-8 (Type UX) | 3,000/Tape & Reel |

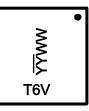
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

 See http://www.diodes.com/quality/lead_free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



<u>T6</u>V= Product Type Marking Code <u>YY</u>WW = Date Code Marking <u>YY</u> = Last Two Digits of Year (ex: 18 = 2018) WW = Week Code (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|---|---|------------------|------------|----|
| Drain-Source Voltage | V _{DSS} | 60 | V | |
| Gate-Source Voltage | | V _{GSS} | ±16 | V |
| | T _A = +25°C T _A = +70°C | ID | 9.5 7.6 | А |
| Continuous Drain Current (Note 5) V_{GS} = 10V | T _C = +25°C T _C = +100°C | I _D | 35 22 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | | I _{DM} | 60 | А |
| Maximum Continuous Body Diode Forward Current (Note 5) | | I _S | 2 | А |
| Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%) | I _{SM} | 60 | А | |
| Avalanche Current, L = 0.1mH | I _{AS} | 17 | А | |
| Avalanche Energy, L = 0.1mH | | E _{AS} | 14.5 | mJ |
| V _{DS} Spike | t = 10µs | VSPIKE | 75 | V |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|--|----------------------------------|----------------------------------|-------------|------|
| Total Dower Dissinction (Note 5) | T _A = +25°C | D- | 2.2 | W |
| Total Power Dissipation (Note 5) | $T_{\rm C} = +25^{\circ}{\rm C}$ | PD | 30 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | Р | 57 | °C/W |
| mermai Resistance, Junction to Ambient (Note 5) | t<10s | $R_{	hetaJA}$ | 35 | |
| Thermal Resistance, Junction to Case (Note 5) | | $R_{\theta JC}$ | 4.2 | |
| Operating and Storage Temperature Range | | T _{J,} T _{STG} | -55 to +150 | °C |

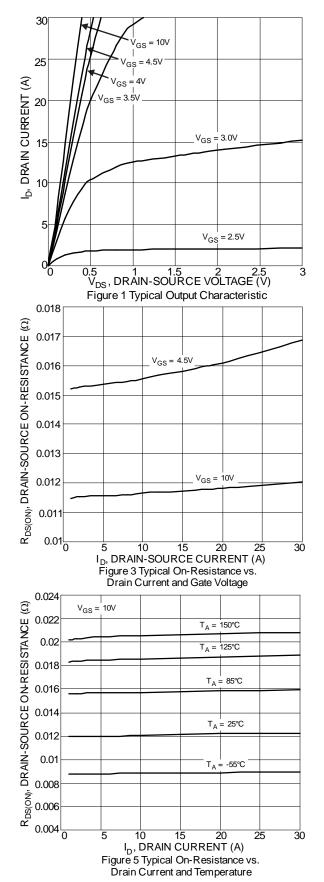
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

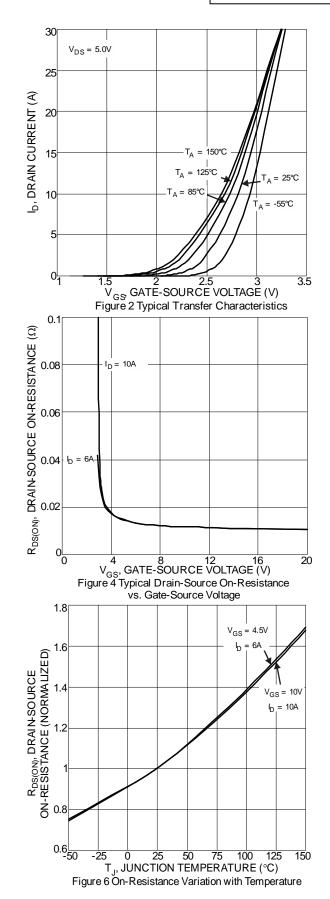
| | | | | | | • | |
|--|--------------------------|-----|------|-----|-------|--|--|
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
| OFF CHARACTERISTICS (Note 6) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 60 | — | _ | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current | IDSS | | _ | 1 | μA | $V_{DS} = 48V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | - | — | ±10 | μA | $V_{GS} = \pm 16V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 6) | - | | | | | * | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.5 | _ | 2.5 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | Р | | 11.7 | 16 | mΩ | $V_{GS} = 10V, I_D = 10A$ | |
| | R _{DS(ON)} | | 15.7 | 22 | 11112 | $V_{GS} = 4.5V, I_D = 6A$ | |
| Diode Forward Voltage | V _{SD} | — | 0.7 | 1.2 | V | $V_{GS} = 0V, I_{S} = 1A$ | |
| DYNAMIC CHARACTERISTICS (Note 7) | | | | | | | |
| Input Capacitance | Ciss | _ | 1103 | _ | pF | $V_{DS} = 30V, V_{GS} = 0V,$ f = 1MHz | |
| Output Capacitance | Coss | _ | 251 | _ | pF | | |
| Reverse Transfer Capacitance | Crss | | 20 | | pF | | |
| Gate Resistance | Rg | | 1.5 | | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | | 8.9 | | nC | | |
| Total Gate Charge (V _{GS} = 10V) | Qg | - | 18.9 | - | nC | Vps = 30V. lp = 10A | |
| Gate-Source Charge | Q _{gs} | | 3 | | nC | $v_{DS} = 30v$, $I_D = 10A$ | |
| Gate-Drain Charge | Q _{gd} | - | 2.8 | - | nC | 7 | |
| Turn-On Delay Time | t _{D(ON)} | — | 4.1 | _ | ns | | |
| Turn-On Rise Time | t _R | — | 7.1 | _ | ns | $V_{GS} = 10V, V_{DS} = 30V,$ | |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 19.5 | _ | ns | $R_{g} = 6\Omega, I_{D} = 10A$ | |
| Turn-Off Fall Time | t _F | | 8.6 | | ns |] | |
| Body Diode Reverse Recovery Time | t _{RR} | _ | 21.2 | _ | ns | | |
| Body Diode Reverse Recovery Charge | Q _{RR} | | 13.2 | | nC | I _F = 10A, di/dt = 100A/μs | |

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate. 6. Short duration pulse test used to minimize self-heating effect.

7. Guaranteed by design. Not subject to product testing.

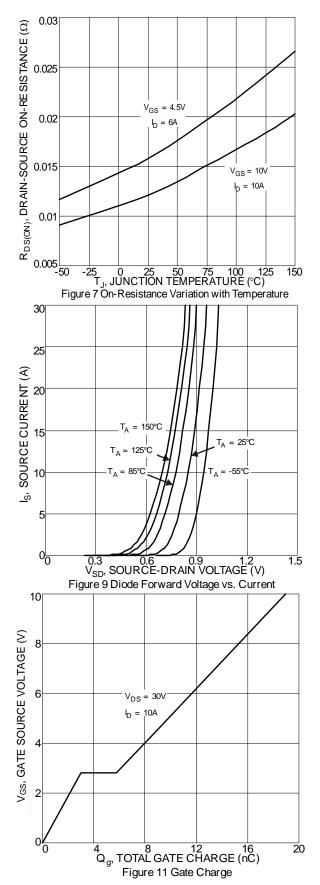


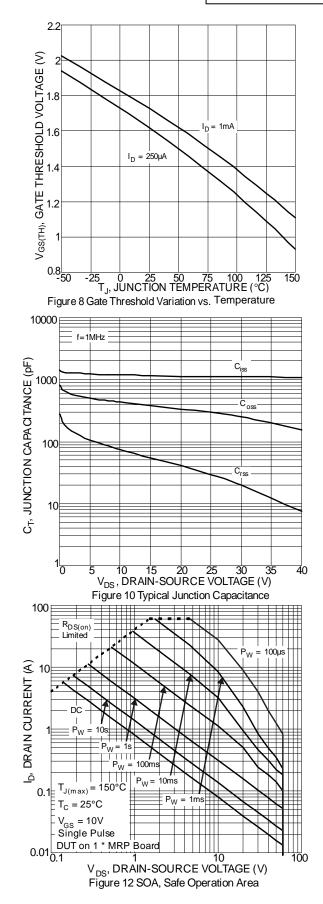




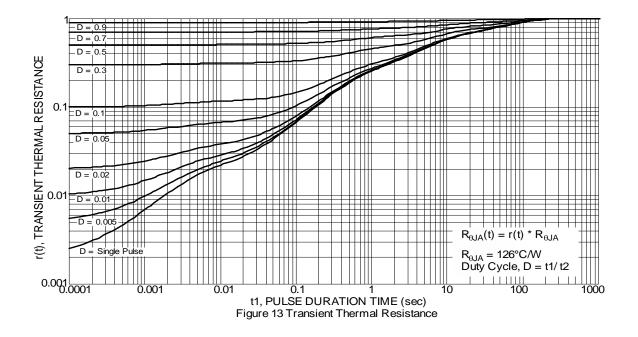


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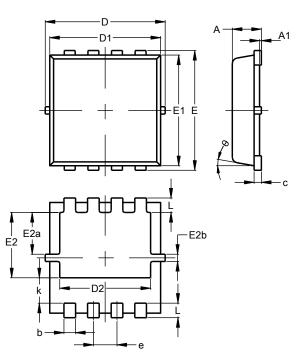






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



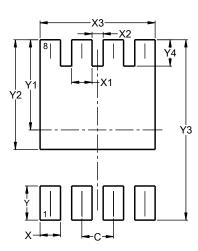
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|---------------|-------|------|--|
| PowerDI3333-8 | (Type | UA) | |

| PowerDl3333-8 (Type UX) | | | | |
|----------------------------|------|---------|------|--|
| Dim | Min | Max | Тур | |
| Α | 0.75 | 0.85 | 0.80 | |
| A1 | 0.00 | 0.05 | | |
| b | 0.25 | 0.40 | 0.32 | |
| С | 0.10 | 0.25 | 0.15 | |
| D | 3.20 | 3.40 | 3.30 | |
| D1 | 2.95 | 3.15 | 3.05 | |
| D2 | 2.30 | 2.70 | 2.50 | |
| Е | 3.20 | 3.40 | 3.30 | |
| E1 | 2.95 | 3.15 | 3.05 | |
| E2 | 1.60 | 2.00 | 1.80 | |
| E2a | 0.95 | 1.35 | 1.15 | |
| E2b | 0.10 | 0.30 | 0.20 | |
| е | 0 | .65 BS0 | 0 | |
| k | 0.50 | 0.90 | 0.70 | |
| L | 0.30 | 0.50 | 0.40 | |
| θ | 0° | 12° | 10° | |
| All Dimensions in mm | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8 (Type UX)



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 0.650 |
| Х | 0.420 |
| X1 | 0.420 |
| X2 | 0.230 |
| X3 | 2.370 |
| Y | 0.700 |
| Y1 | 1.850 |
| Y2 | 2.250 |
| Y3 | 3.700 |
| Y4 | 0.540 |



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